

# TC74LCX126F, TC74LCX126FT, TC74LCX126FK

## Low-Voltage Quad Bus Buffer with 5-V Tolerant Inputs and Outputs

The TC74LCX126 is a high-performance CMOS quad bus buffers. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

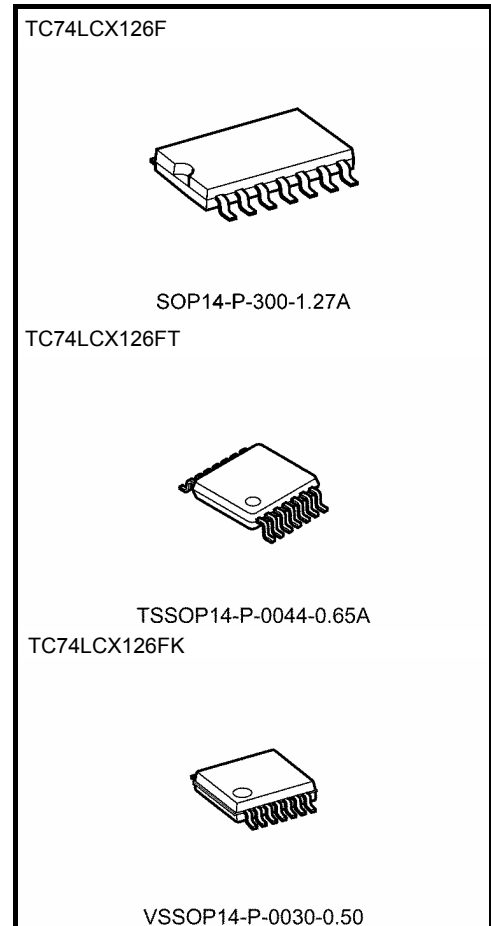
The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5-V supply environment for inputs.

This device requires the 3-state control input (OE) to be set high to place the output into the high impedance state.

All inputs are equipped with protection circuits against static discharge.

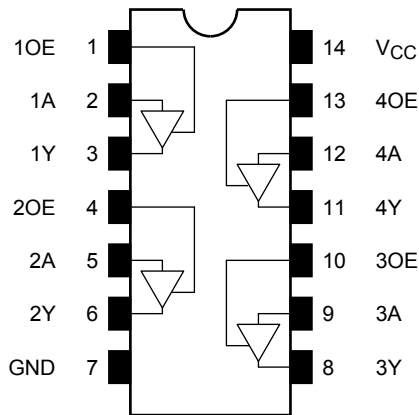
### Features

- Low-voltage operation:  $V_{CC} = 2.0$  to  $3.6$  V
- High-speed operation:  $t_{pd} = 6.0$  ns (max) ( $V_{CC} = 3.0$  to  $3.6$  V)
- Output current:  $|I_{OH}|/I_{OL} = 24$  mA (min) ( $V_{CC} = 3.0$  V)
- Latch-up performance:  $-500$  mA
- Available in JEDEC SOP, JEITA SOP, TSSOP and VSSOP (US)
- Power-down protection is provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 126 type

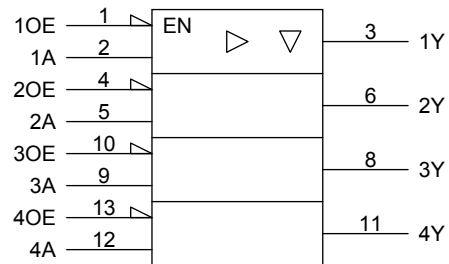


Weight	
SOP14-P-300-1.27A	: 0.18 g (typ.)
TSSOP14-P-0044-0.65A	: 0.06 g (typ.)
VSSOP14-P-0030-0.50	: 0.02 g (typ.)

## Pin Assignment (top view)



## IEC Logic Symbol



## Truth Table

Inputs		Outputs
OE	A	Y
L	X	Z
H	L	L
H	H	H

X: Don't care

Z: High impedance

## Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	$V_{CC}$	-0.5 to 7.0	V
DC input voltage	$V_{IN}$	-0.5 to 7.0	V
DC output voltage	$V_{OUT}$	-0.5 to 7.0 (Note 2)	V
		-0.5 to $V_{CC} + 0.5$ (Note 3)	
Input diode current	$I_{IK}$	-50	mA
Output diode current	$I_{OK}$	$\pm 50$ (Note 4)	mA
DC output current	$I_{OUT}$	$\pm 50$	mA
Power dissipation	$P_D$	180	mW
DC $V_{CC}$ /ground current	$I_{CC}/I_{GND}$	$\pm 100$	mA
Storage temperature	$T_{stg}$	-65 to 150	$^{\circ}C$

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating range (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in OFF state

Note 3: High or low state.  $I_{OUT}$  absolute maximum rating must be observed.

Note 4:  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$

## Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V <sub>CC</sub>	2.0 to 3.6	V
		1.5 to 3.6 (Note 2)	
Input voltage	V <sub>IN</sub>	0 to 5.5	V
Output voltage	V <sub>OUT</sub>	0 to 5.5 (Note 3)	V
		0 to V <sub>CC</sub> (Note 4)	
Output current	I <sub>OH</sub> /I <sub>OL</sub>	±24 (Note 5)	mA
		±12 (Note 6)	
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.  
Unused inputs must be tied to either V<sub>CC</sub> or GND.

Note 2: Data retention only

Note 3: Output in OFF state

Note 4: High or low state

Note 5: V<sub>CC</sub> = 3.0 to 3.6 V

Note 6: V<sub>CC</sub> = 2.7 to 3.0 V

Note 7: V<sub>IN</sub> = 0.8 to 2.0 V, V<sub>CC</sub> = 3.0 V

## Electrical Characteristics

### DC Characteristics (Ta = -40 to 85°C)

Characteristics		Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit	
Input voltage	H-level	V <sub>IH</sub>	—	2.7 to 3.6	2.0	—	V	
	L-level	V <sub>IL</sub>	—	2.7 to 3.6	—	0.8		
Output voltage	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	2.7 to 3.6	V <sub>CC</sub> - 0.2	—	V
				I <sub>OH</sub> = -12 mA	2.7	2.2	—	
				I <sub>OH</sub> = -18 mA	3.0	2.4	—	
				I <sub>OH</sub> = -24 mA	3.0	2.2	—	
	L-level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	2.7 to 3.6	—	0.2	
				I <sub>OL</sub> = 12 mA	2.7	—	0.4	
				I <sub>OL</sub> = 16 mA	3.0	—	0.4	
				I <sub>OL</sub> = 24 mA	3.0	—	0.55	
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 5.5 V	2.7 to 3.6	—	±5.0	μA	
3-state output OFF state current		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0 to 5.5 V	2.7 to 3.6	—	±5.0	μA	
Power-off leakage current		I <sub>OFF</sub>	V <sub>IN</sub> /V <sub>OUT</sub> = 5.5 V	0	—	10.0	μA	
Quiescent supply current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	2.7 to 3.6	—	10.0	μA	
			V <sub>IN</sub> /V <sub>OUT</sub> = 3.6 to 5.5 V	2.7 to 3.6	—	±10.0		
Increase in I <sub>CC</sub> per input		ΔI <sub>CC</sub>	V <sub>IH</sub> = V <sub>CC</sub> - 0.6 V	2.7 to 3.6	—	500		

## AC Characteristics (Ta = -40 to 85°C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Propagation delay time	t <sub>pLH</sub>	Figure 1, Figure 2	2.7	—	6.5	ns
	t <sub>pHL</sub>		3.3 ± 0.3	1.5	6.0	
Output enable time	t <sub>pZL</sub>	Figure 1, Figure 3	2.7	—	8.0	ns
	t <sub>pZH</sub>		3.3 ± 0.3	1.5	7.0	
Output disable time	t <sub>pLZ</sub>	Figure 1, Figure 3	2.7	—	7.0	ns
	t <sub>pHZ</sub>		3.3 ± 0.3	1.5	6.0	
Output to output skew	t <sub>osLH</sub>	(Note)	2.7	—	—	ns
	t <sub>osHL</sub>		3.3 ± 0.3	—	1.0	

Note: Parameter guaranteed by design.  
 (t<sub>osLH</sub> = |t<sub>pLHm</sub> - t<sub>pLHn</sub>|, t<sub>osHL</sub> = |t<sub>pHLm</sub> - t<sub>pHLn</sub>|)

## Dynamic Switching Characteristics (Ta = 25°C, input: t<sub>r</sub> = t<sub>f</sub> = 2.5 ns, C<sub>L</sub> = 50 pF, R<sub>L</sub> = 500 Ω)

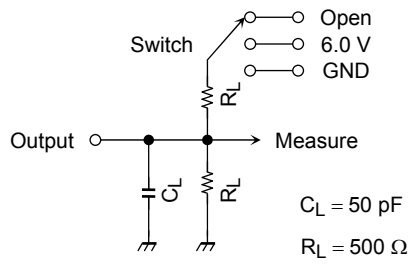
Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Typ.	Unit
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V	3.3	0.8	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V	3.3	0.8	V

## Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Typ.	Unit	
Input capacitance	C <sub>IN</sub>	—	3.3	7	pF	
Output capacitance	C <sub>OUT</sub>	—	3.3	8	pF	
Power dissipation capacitance	C <sub>PD</sub>	f <sub>IN</sub> = 10 MHz	(Note)	3.3	25	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.  
 Average operating current can be obtained by the equation:  
 $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4$  (per gate)

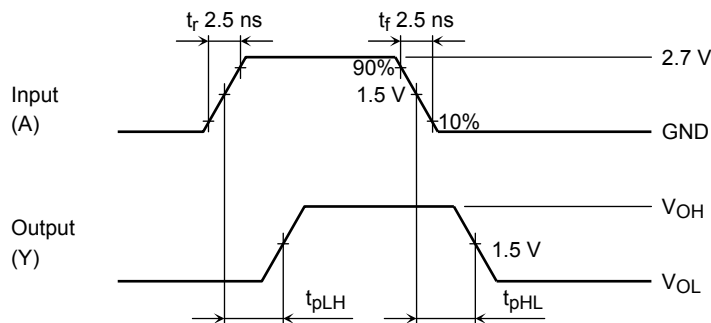
**AC Test Circuit**



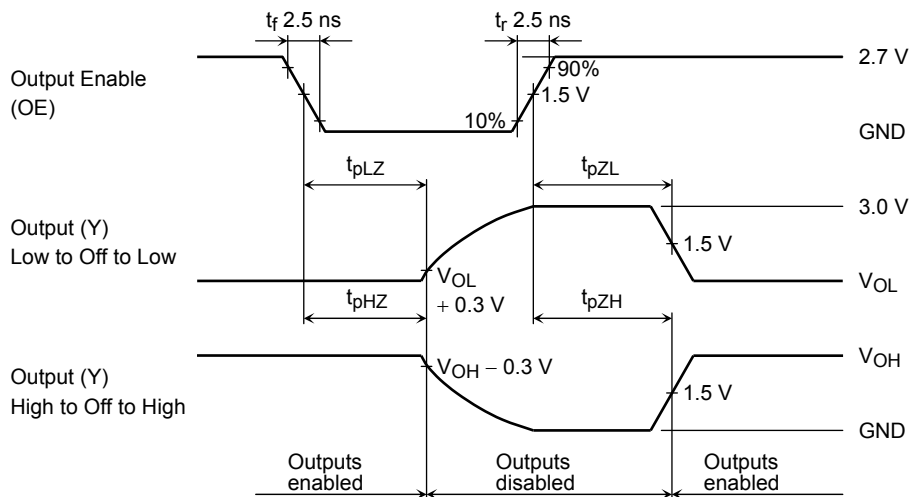
Parameter	Switch
$t_{pLH}, t_{pHL}$	Open
$t_{pLZ}, t_{pZL}$	6.0 V
$t_{pHZ}, t_{pZH}$	GND

**Figure 1**

**AC Waveform**



**Figure 2  $t_{pLH}, t_{pHL}$**



**Figure 3  $t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}$**

## Package Dimensions

SOP14-P-300-1.27A

Unit: mm

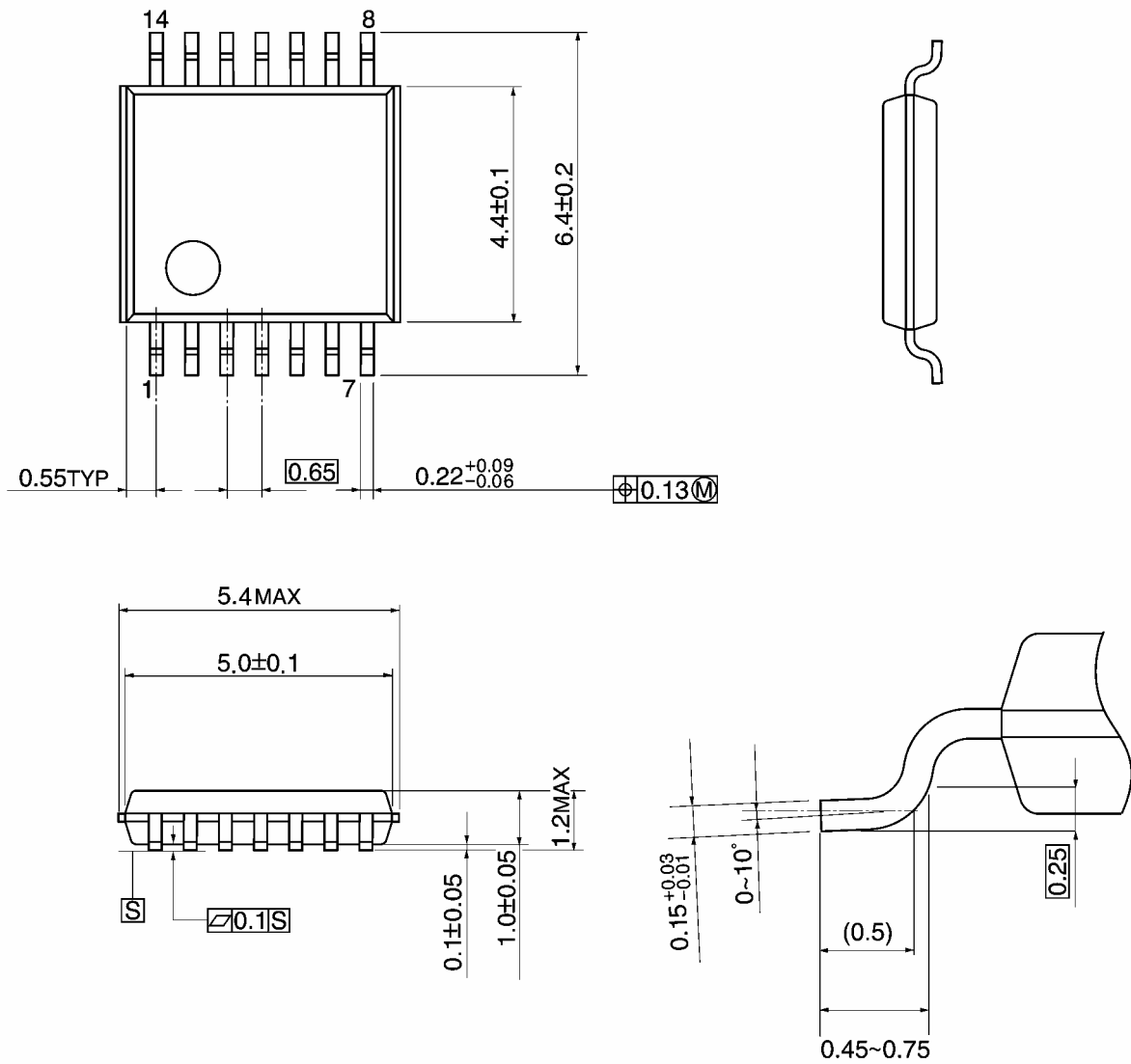


Weight: 0.18 g (typ.)

**Package Dimensions**

TSSOP14-P-0044-0.65A

Unit: mm

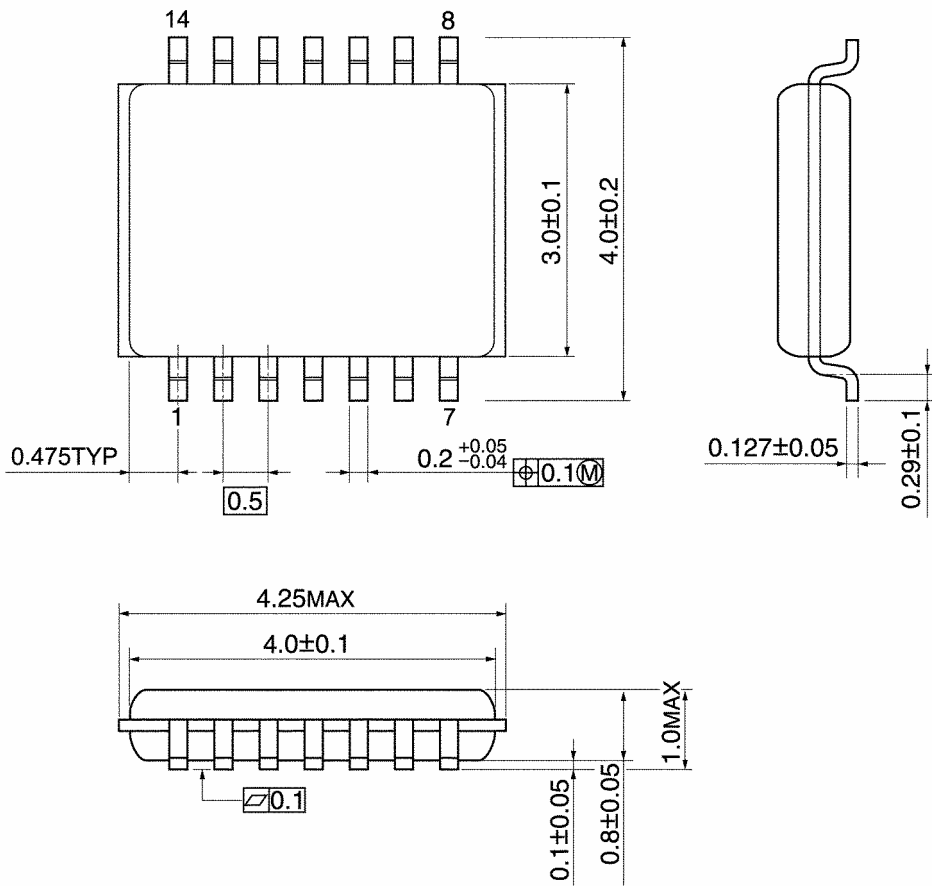


Weight: 0.06 g (typ.)

## Package Dimensions

VSSOP14-P-0030-0.50

Unit: mm



Weight: 0.02 g (typ.)



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20070701-EN GENERAL

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